# BT138-600E

4Q Triac 25 July 2012

**Product data sheet** 

### 1. Product profile

### 1.1 General description

Planar passivated sensitive gate four quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in general purpose bidirectional switching and phase control applications. This sensitive gate "series E" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

#### 1.2 Features and benefits

- Direct triggering from low power drivers and logic ICs
- High blocking voltage capability
- Planar passivated for voltage ruggedness and reliability
- Sensitive gate
- Triggering in all four quadrants

### 1.3 Applications

- General purpose motor control
- General purpose switching

#### 1.4 Quick reference data

Table 1. Quick reference data

| Symbol              | Parameter                                | Conditions   | Min | Тур | Max | Unit |
|---------------------|--|--|-----|-----|-----|------|
| $V_{DRM}$           | repetitive peak off-<br>state voltage    |  | -   | -   | 600 | V    |
| I <sub>TSM</sub>    | non-repetitive peak on-<br>state current | full sine wave; $T_{j(init)} = 25 ^{\circ}C$ ;<br>$t_p = 20  \text{ms}$ ; Fig. 4; Fig. 5       | -   | -   | 95  | А    |
| T <sub>j</sub>      | junction temperature                     |  | -   | -   | 125 | °C   |
| I <sub>T(RMS)</sub> | RMS on-state current                     | full sine wave; $T_{mb} \le 99 \text{ °C}$ ; Fig. 1;<br>Fig. 2; Fig. 3                         | -   | -   | 12  | А    |
| Static charact      | eristics                                 |  |     |     |     |      |
| I <sub>GT</sub>     | gate trigger current                     | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2+ \text{ G+;}$<br>$T_j = 25 \text{ °C; } Fig. 7$ | -   | 2.5 | 10  | mA   |
|                     |  | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2 + G-;$<br>$T_j = 25 \text{ °C; } Fig. 7$        | -   | 4   | 10  | mA   |





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| Symbol              | Parameter                         | Conditions   | Min | Тур | Max | Unit |
|---------------------|-----------------------------------|--|-----|-----|-----|------|
|                     |                                   | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2-\text{ G-;}$<br>$T_j = 25 \text{ °C; } Fig. 7$              | -   | 5   | 10  | mA   |
|                     |                                   | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2-\text{ G+;}$ $T_j = 25 \text{ °C; } Fig. 7$                 | -   | 11  | 25  | mA   |
| Dynamic char        | acteristics                       |  |     |     |     |      |
| dV <sub>D</sub> /dt | rate of rise of off-state voltage | $V_{DM}$ = 402 V; $T_j$ = 125 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit | -   | 150 | -   | V/µs |

### 2. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description                    | Simplified outline | Graphic symbol |
|-----|--------|--------------------------------|--------------------|----------------|
| 1   | T1     | main terminal 1                | mb                 | T2             |
| 2   | T2     | main terminal 2                | 7 7 9              | sym051         |
| 3   | G      | gate                           |                    | J              |
| mb  | T2     | mounting base; main terminal 2 |                    |                |
|     |        |                                | TO-220AB (SOT78)   |                |

## 3. Ordering information

Table 3. Ordering information

| Type number | Package  |  |         |  |  |
|-------------|----------|--|---------|--|--|
|             | Name     | Description  | Version |  |  |
| BT138-600E  | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78   |  |  |

### 4. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol              | Parameter                         | Conditions  | Min | Max | Unit |
|---------------------|-----------------------------------|---|-----|-----|------|
| $V_{DRM}$           | repetitive peak off-state voltage |   | -   | 600 | V    |
| I <sub>T(RMS)</sub> | RMS on-state current              | full sine wave; $T_{mb} \le 99$ °C; Fig. 1;<br>Fig. 2; Fig. 3 | -   | 12  | А    |

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| Symbol              | Parameter                            | Conditions   | Min | Max | Unit             |
|---------------------|--------------------------------------|--|-----|-----|------------------|
| I <sub>TSM</sub>    | non-repetitive peak on-state current | full sine wave; $T_{j(init)}$ = 25 °C;<br>$t_p$ = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u> | -   | 95  | A                |
|                     |                                      | full sine wave; $T_{j(init)}$ = 25 °C;<br>$t_p$ = 16.7 ms                              | -   | 105 | A                |
| l <sup>2</sup> t    | I <sup>2</sup> t for fusing          | t <sub>p</sub> = 10 ms; sine-wave pulse  | -   | 45  | A <sup>2</sup> s |
| dl <sub>T</sub> /dt | rate of rise of on-state current     | $I_T$ = 20 A; $I_G$ = 0.2 A; $dI_G/dt$ = 0.2 A/ $\mu$ s; T2+ G+                        | -   | 50  | A/µs             |
|                     |                                      | $I_T$ = 20 A; $I_G$ = 0.2 A; $dI_G/dt$ = 0.2 A/ $\mu$ s; T2+ G-                        | -   | 50  | A/µs             |
|                     |                                      | $I_T$ = 20 A; $I_G$ = 0.2 A; $dI_G/dt$ = 0.2 A/ $\mu$ s; T2- G-                        | -   | 50  | A/µs             |
|                     |                                      | $I_T$ = 20 A; $I_G$ = 0.2 A; $dI_G/dt$ = 0.2 A/ $\mu$ s; T2- G+                        | -   | 10  | A/µs             |
| I <sub>GM</sub>     | peak gate current                    |  | -   | 2   | Α                |
| $P_{GM}$            | peak gate power                      |  | -   | 5   | W                |
| P <sub>G(AV)</sub>  | average gate power                   | over any 20 ms period  | -   | 0.5 | W                |
| T <sub>stg</sub>    | storage temperature                  |  | -40 | 150 | °C               |
| Tj                  | junction temperature                 |  | -   | 125 | °C               |

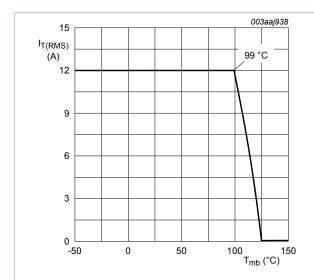
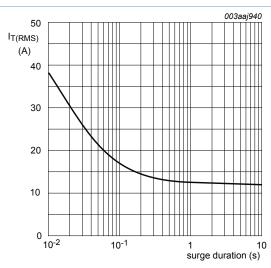


Fig. 1. RMS on-state current as a function of mounting base temperature; maximum values



f = 50 Hz;  $T_{mb}$  = 99 °C

Fig. 2. RMS on-state current as a function of surge duration; maximum values

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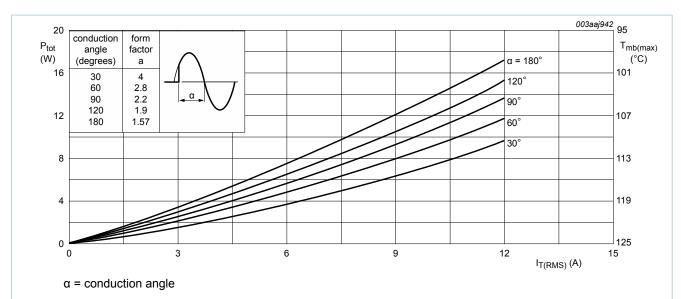


Fig. 3. Total power dissipation as a function of RMS on-state current; maximum values

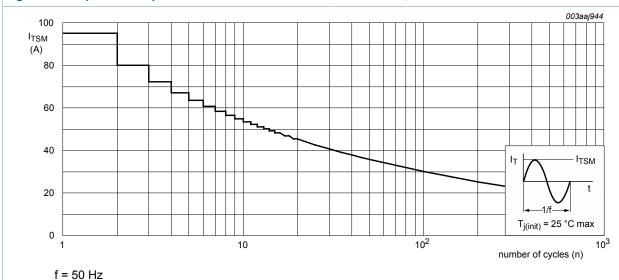
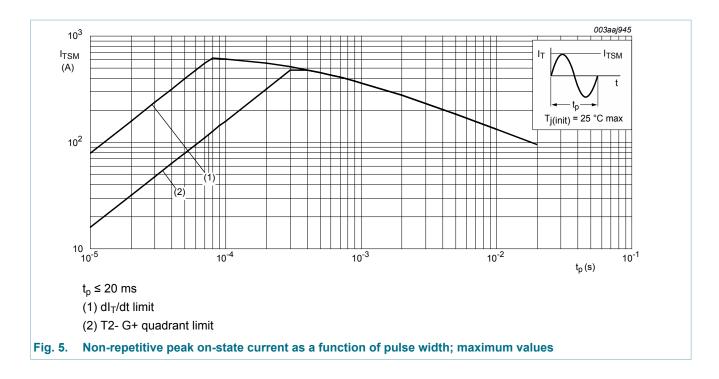


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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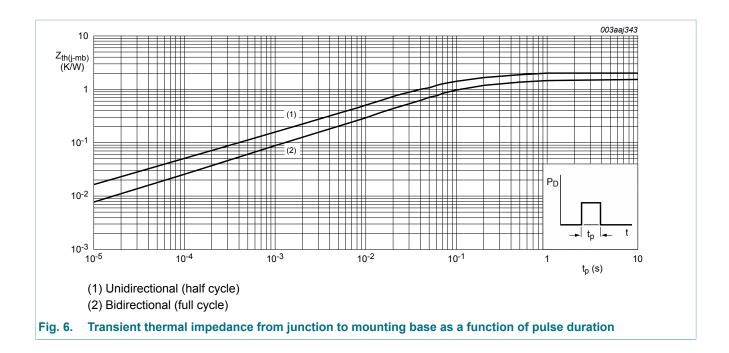


### 5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol                | Parameter                                   | Conditions         | Min | Тур | Max | Unit |
|-----------------------|---|--------------------|-----|-----|-----|------|
| R <sub>th(j-mb)</sub> | thermal resistance                          | full cycle; Fig. 6 | -   | -   | 1.5 | K/W  |
|                       | from junction to mounting base              | half cycle; Fig. 6 | -   | -   | 2   | K/W  |
| R <sub>th(j-a)</sub>  | thermal resistance from junction to ambient | in free air        | -   | 60  | -   | K/W  |

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### 6. Characteristics

Table 6. Characteristics

| Symbol          | Parameter            | Conditions   | Min | Тур | Max  | Unit |
|-----------------|----------------------|--|-----|-----|------|------|
| Static char     | acteristics          |  |     | '   |      | _    |
| I <sub>GT</sub> | gate trigger current | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+ G+;$<br>$T_j = 25 \text{ °C}; Fig. 7$                            | -   | 2.5 | 10   | mA   |
|                 |                      | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+ \text{ G-};$<br>$T_j = 25 \text{ °C}; Fig. 7$                    | -   | 4   | 10   | mA   |
|                 |                      | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2- G-};$<br>$T_j = 25 ^{\circ}\text{C}; \text{ Fig. 7}$      | -   | 5   | 10   | mA   |
|                 |                      | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2- G+};$<br>$T_j = 25 ^{\circ}\text{C}; \text{ Fig. 7}$      | -   | 11  | 25   | mA   |
| IL              | latching current     | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G+;$<br>$T_j = 25 \text{ °C}; Fig. 8$                            | -   | -   | 30   | mA   |
|                 |                      | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ \text{ G-};$<br>$T_j = 25 \text{ °C}; Fig. 8$                    | -   | -   | 40   | mA   |
|                 |                      | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G-};$<br>$T_j = 25 ^{\circ}\text{C}; \text{ Fig. 8}$      | -   | -   | 30   | mA   |
|                 |                      | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G+};$<br>$T_j = 25 \text{ °C}; \underline{\text{Fig. 8}}$ | -   | -   | 40   | mA   |
| I <sub>H</sub>  | holding current      | V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>   | -   | -   | 30   | mA   |
| V <sub>T</sub>  | on-state voltage     | I <sub>T</sub> = 15 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>  | -   | 1.4 | 1.65 | V    |

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| Symbol              | Parameter                         | Conditions   | Min  | Тур | Max | Unit |
|---------------------|-----------------------------------|--|------|-----|-----|------|
| $V_{GT}$            | gate trigger voltage              | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$<br>Fig. 11                                 | -    | 0.7 | 1.5 | V    |
|                     |                                   | $V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_j = 125 \text{ °C};$<br>Fig. 11                               | 0.25 | 0.4 | -   | V    |
| I <sub>D</sub>      | off-state current                 | V <sub>D</sub> = 600 V; T <sub>j</sub> = 125 °C  | -    | 0.1 | 0.5 | mA   |
| Dynamic ch          | naracteristics                    |  |      |     |     |      |
| dV <sub>D</sub> /dt | rate of rise of off-state voltage | $V_{DM}$ = 402 V; $T_j$ = 125 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit | -    | 150 | -   | V/µs |
| t <sub>gt</sub>     | gate-controlled turn-on time      | $I_{TM}$ = 16 A; $V_D$ = 600 V; $I_G$ = 0.1 A; $dI_G/dt$ = 5 A/ $\mu$ s                                    | -    | 2   | -   | μs   |

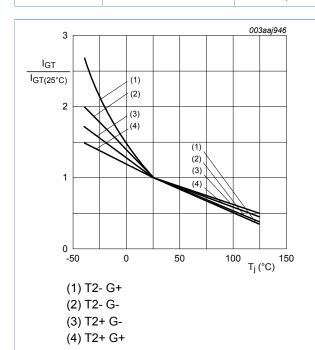


Fig. 7. Normalized gate trigger current as a function of junction temperature

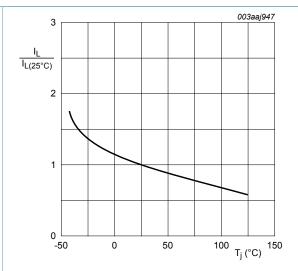


Fig. 8. Normalized latching current as a function of junction temperature

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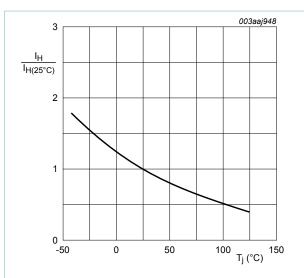
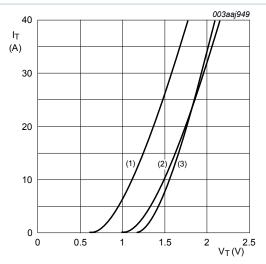


Fig. 9. Normalized holding current as a function of junction temperature



 $V_o = 1.175 \text{ V}; R_s = 0.0316 \Omega$ 

(1)  $T_j$  = 125 °C; typical values

(2)  $T_j$  = 125 °C; maximum values

(3) T<sub>i</sub> = 25 °C; maximum values

Fig. 10. On-state current as a function of on-state voltage

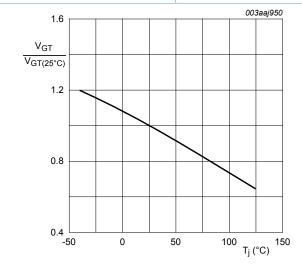
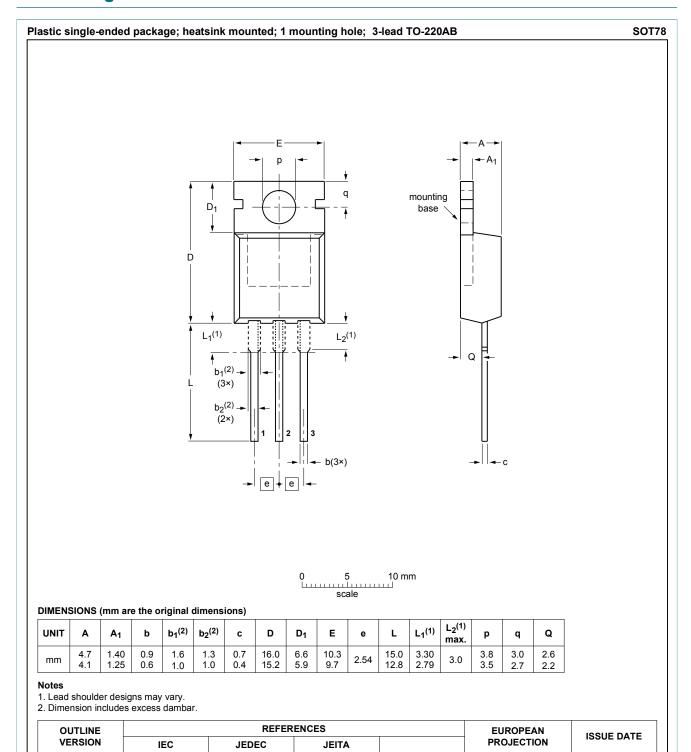


Fig. 11. Normalized gate trigger voltage as a function of junction temperature

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### 7. Package outline



### Fig. 12. TO-220AB (SOT78)

SOT78

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3-lead TO-220AB

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